

Dual high slew rate operational amplifier

BA4560/BA4560F/BA4560N

The BA4560, BA4560F, and BA4560N are dual operational amplifiers which achieve approximately twice the high output current of the BA4558, as well as featuring a higher slew rate of $4V/\mu s$, a gain band width of 10MHz, and an improved frequency characteristic. The following packages are available : 8-pin DIP (BA4560), 8-pin SOP (BA4560F), and 8-pin SIP (BA4560N).

● Applications

Active filters

Audio amplifiers

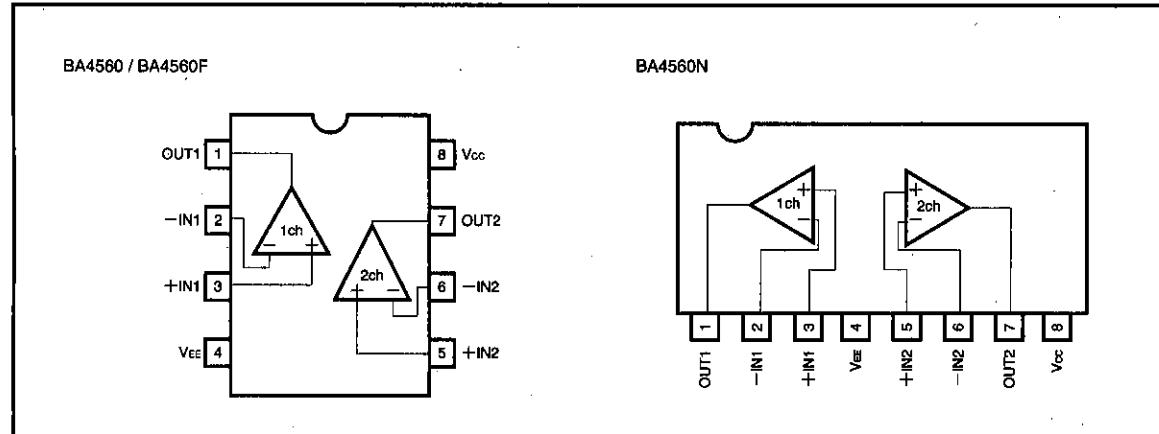
VCOs

Other electronic circuits

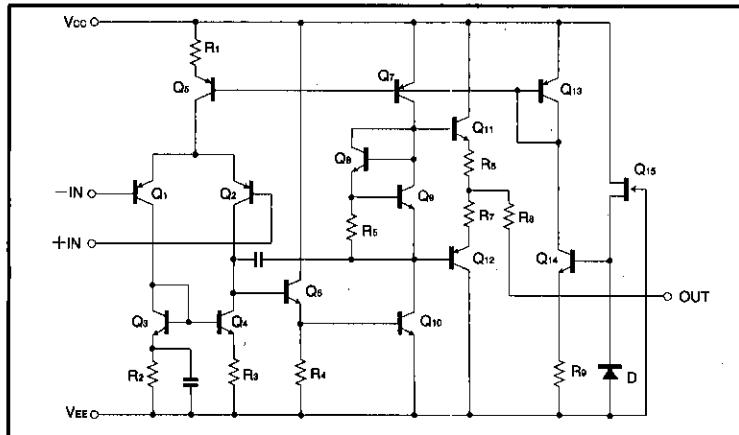
● Features

- 1) Built-in output short-circuit protection circuit.
- 2) Internal phase correction.
- 3) No latch-up.
- 4) Wide range of common mode and differential voltage.
- 5) High gain and low noise.

● Block diagram



● Internal circuit configuration diagram

● Absolute maximum ratings ($T_a=25^\circ\text{C}$)

| Parameter | Symbol | Limits | | | Unit |
|----------------------------|-----------|-----------------------|----------|----------|------------------|
| | | BA4560 | BA4560F | BA4560N | |
| Power supply voltage | V_{CC} | ± 18 | ± 18 | ± 18 | V |
| Power dissipation | P_d | 600* | 550* | 900* | mW |
| Differential input voltage | V_{ID} | $\pm V_{CC}$ | | | V |
| In-phase input voltage | V_I | $-V_{CC} \sim V_{CC}$ | | | V |
| Operating temperature | T_{OPR} | $-40 \sim 85$ | | | $^\circ\text{C}$ |
| Storage temperature | T_{STG} | $-55 \sim 125$ | | | $^\circ\text{C}$ |

* For P_d values, please see P_d characteristic diagram. Values are those when BA4560F is mounted on a glass epoxy PCB (50 mm x 50 mm x 1.6 mm).

● Electrical characteristics (unless otherwise noted, $T_a=25^\circ\text{C}$, $V_{CC}=+15\text{V}$, $V_{EE}=-15\text{V}$)

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|--------------------------------------|-----------|----------|----------|------|------------------------|---|
| Input offset voltage | V_{IO} | — | 0.5 | 6.0 | mV | $R_S \leq 10\text{k}\Omega$ |
| Input offset current | I_{IO} | — | 5 | 200 | nA | — |
| Input bias current | I_B | — | 50 | 500 | nA | — |
| High-amplitude voltage gain | A_V | 86 | 100 | — | dB | $R_L \geq 2\text{k}\Omega$, $V_o = \pm 10\text{V}$ |
| Common mode input voltage range | V_{ICM} | ± 12 | ± 14 | — | V | — |
| Quiescent circuit current | I_Q | — | 4 | 7.5 | mA | $R_L = \infty$ All Op - Amps |
| Maximum output voltage | V_{OM} | ± 12 | ± 14 | — | V | $R_L \geq 10\text{k}\Omega$ |
| Maximum output voltage | V_{OM} | ± 10 | ± 13 | — | V | $R_L \geq 2\text{k}\Omega$ |
| Common mode rejection ratio | CMRR | 70 | 90 | — | dB | $R_S \leq 10\text{k}\Omega$ |
| Power supply voltage rejection ratio | PSRR | — | 30 | 150 | $\mu\text{V/V}$ | $R_S \leq 10\text{k}\Omega$ |
| Slew rate | S. R. | — | 4.0 | — | $\text{V}/\mu\text{s}$ | $A_V=1$, $R_L=2\text{k}\Omega$ |
| Input noise voltage | V_n | — | — | 2.2 | μV | — |
| Voltage gain band width | GBW | — | 10 | — | MHz | $f=10\text{kHz}$ |
| Maximum frequency | f_T | — | 2 | — | MHz | — |

● Electrical characteristic curves

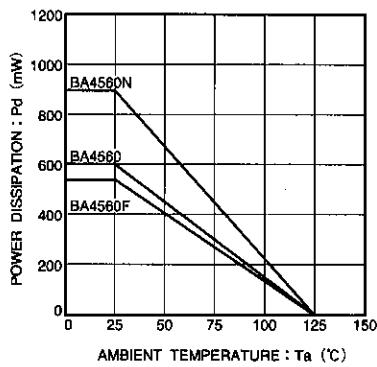


Fig.1 Power dissipation - ambient temperature characteristic

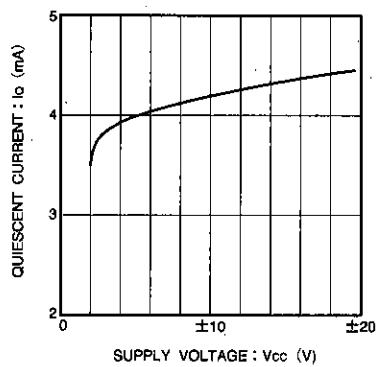


Fig.2 Quiescent current - power supply voltage characteristic

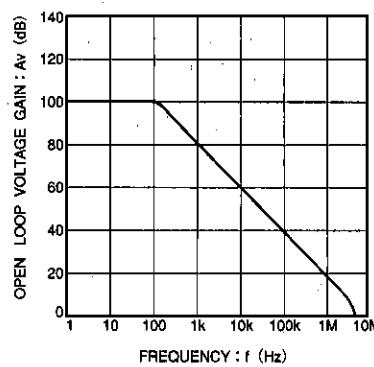


Fig.3 Open loop voltage gain - frequency characteristic

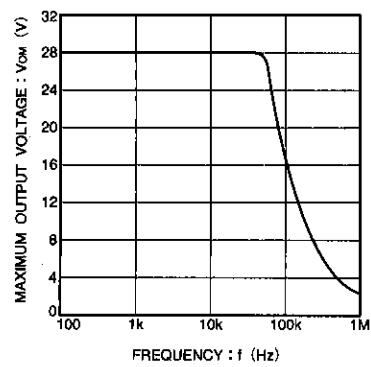


Fig.4 Maximum output voltage - frequency characteristic

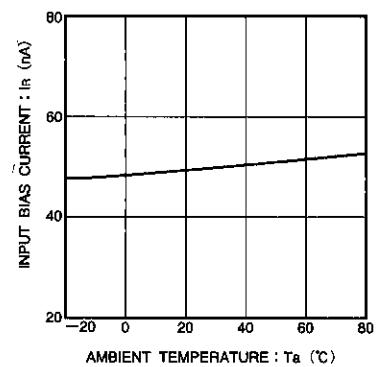


Fig.5 Input bias current - ambient temperature characteristic

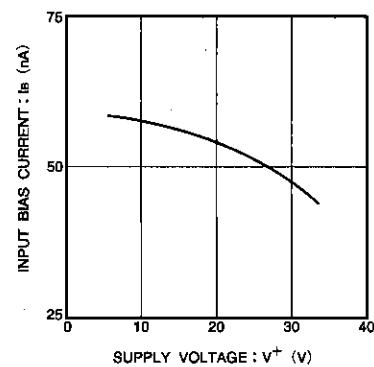


Fig.6 Input bias current - power supply voltage characteristic

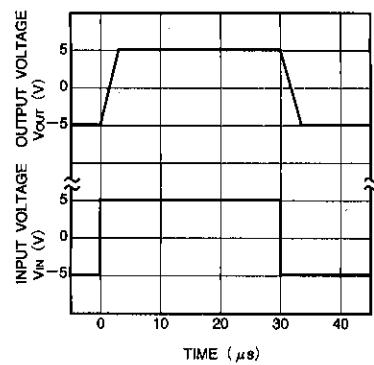


Fig.7 Output response characteristic

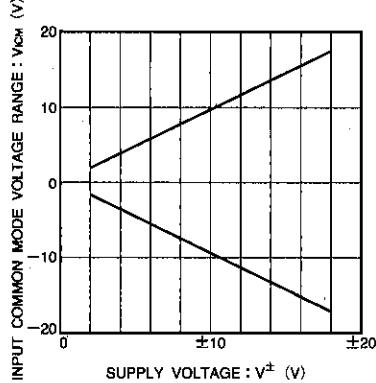


Fig.8 Common mode input voltage - power supply voltage characteristic

● Operation notes

Unused circuit connections

If there are any circuits which are not being used, we recommend making connections as shown in Figure 9, with the non-inverted input pin connected to the potential within the in-phase input voltage range (V_{ICM}).

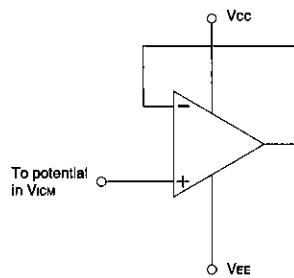


Fig.9 Unused circuit connections

● External dimensions (Units: mm)

